

UNIVERSITY OF CALIFORNIA
College of Engineering
Department of Electrical Engineering and Computer Sciences

EE40
Summer 09

Frank Liao

MIDTERM EXAMINATION #2

Time allotted: 100 minutes

NAME: _____
(print) Last First Student ID#

LAB SECTION: _____ / _____
Days / Time

I acknowledge that the UC rules on academic honesty apply. _____
Signature

INSTRUCTIONS:

1. **SHOW YOUR WORK.** Partial credit will be given only if your methods are clear to the grader.
2. **Clearly mark (BOX or UNDERLINE) your answers.**
3. **Specify the units on answers whenever appropriate.** Points will be deducted for missing units.
4. **Closed book, closed notes.** You are allowed TWO 8.5" x 11" sheet of notes. Calculators are allowed.

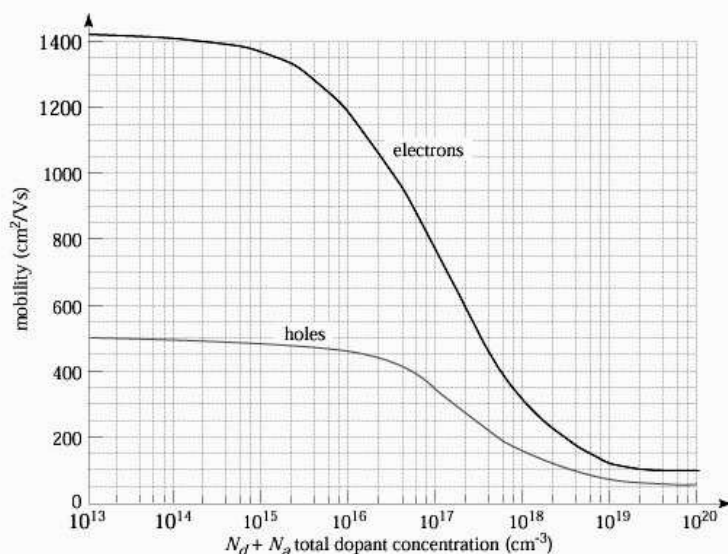
PHYSICAL CONSTANTS

Description	Symbol	Value
Electronic charge	q	1.6×10^{-19} C
Boltzmann's constant	k	8.62×10^{-5} eV/K
Thermal voltage at 300K	$V_T = kT/q$	0.026 V

PROPERTIES OF SILICON AT 300K

Description	Symbol	Value
Intrinsic carrier concentration	n_i	10^{10} cm ⁻³
Dielectric permittivity	ϵ_{Si}	1.0×10^{-12} F/cm

Electron and Hole Mobilities in Silicon at 300K



SCORE: 1 _____ / 10

2 _____ / 20

3 _____ / 30

4 _____ / 20

5 _____ / 20

TOTAL: _____ / 100

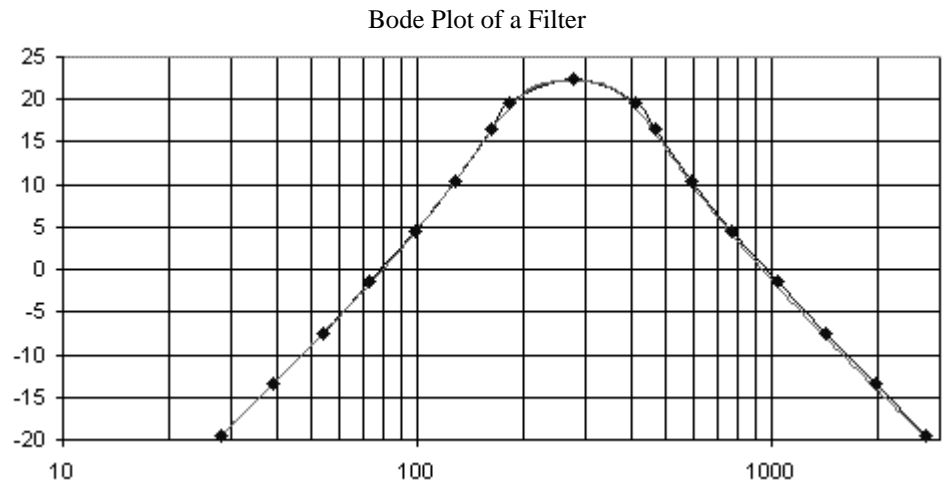
Problem 1 [10 points]: Basic concepts and EE Technology

a) True/False and Multiple Choice. Select only ONE choice. No credit will be given to multiple answers. [2 pts each]

- T F LCD stands for Liquid Capacitance Display.
- T F The MEMS accelerometer uses a differential capacitance to detect motion.
- T F If an RC circuit has a large time constant, τ , then it takes a long time for the capacitor in that circuit to charge and discharge.

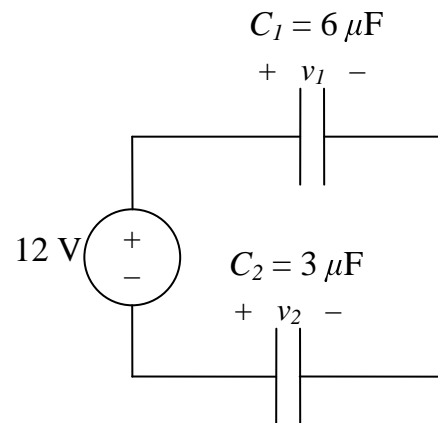
4) What kind of filter is this?

- a) Lowpass
- b) Highpass
- c) Bandpass
- d) Bandreject



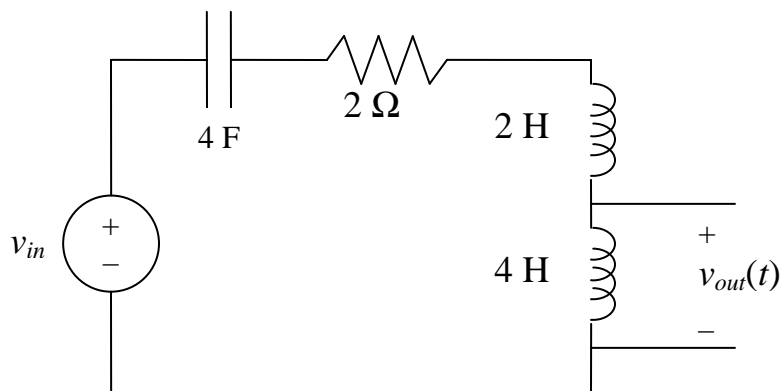
5) What is v_1 , the voltage drop across C_1 ?

- a) 4 V
- b) 8 V
- c) -4 V
- d) -8 V



Problem 2 [20 points]: Phasor Analysis

In the circuit below, $v_{in}(t) = 2 \cos(0.1t + 30^\circ)$.



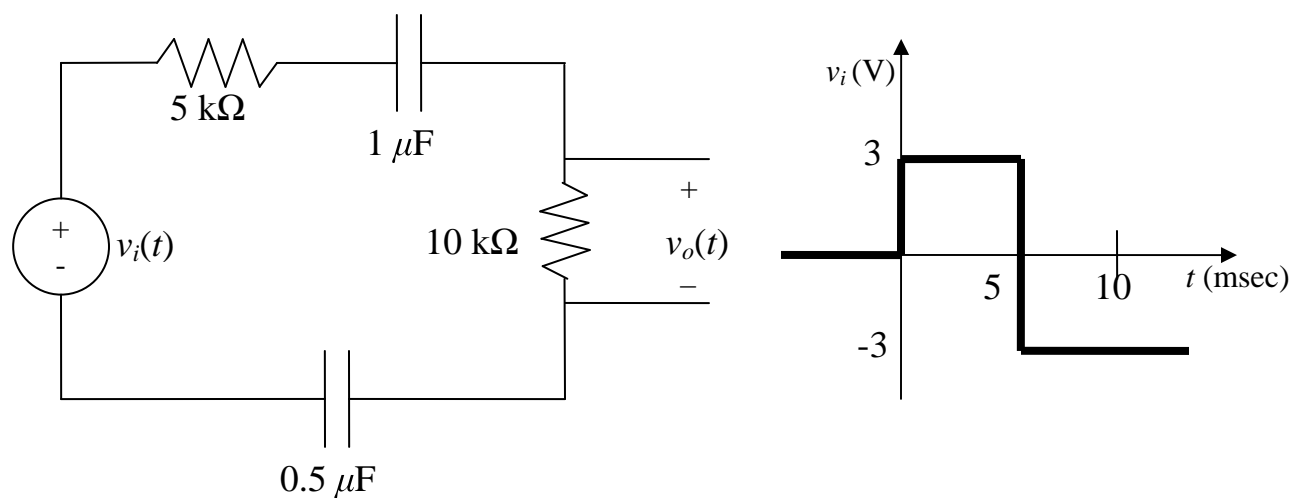
a.) What is $v_{out}(t)$ in cosine form? **[10 pts]**

b.) If $v_{out} / v_{in} = (20 + j2\omega) (40 + j\omega) / j10\omega$, sketch the bode plot of the magnitude of the transfer function, $\mathbf{H}(\omega)$. Label the axes appropriately, denoting critical angles, slopes and plateau values. **[10 pts]**



Problem 3 [30 points]: First-Order Transients

Consider the circuit below:

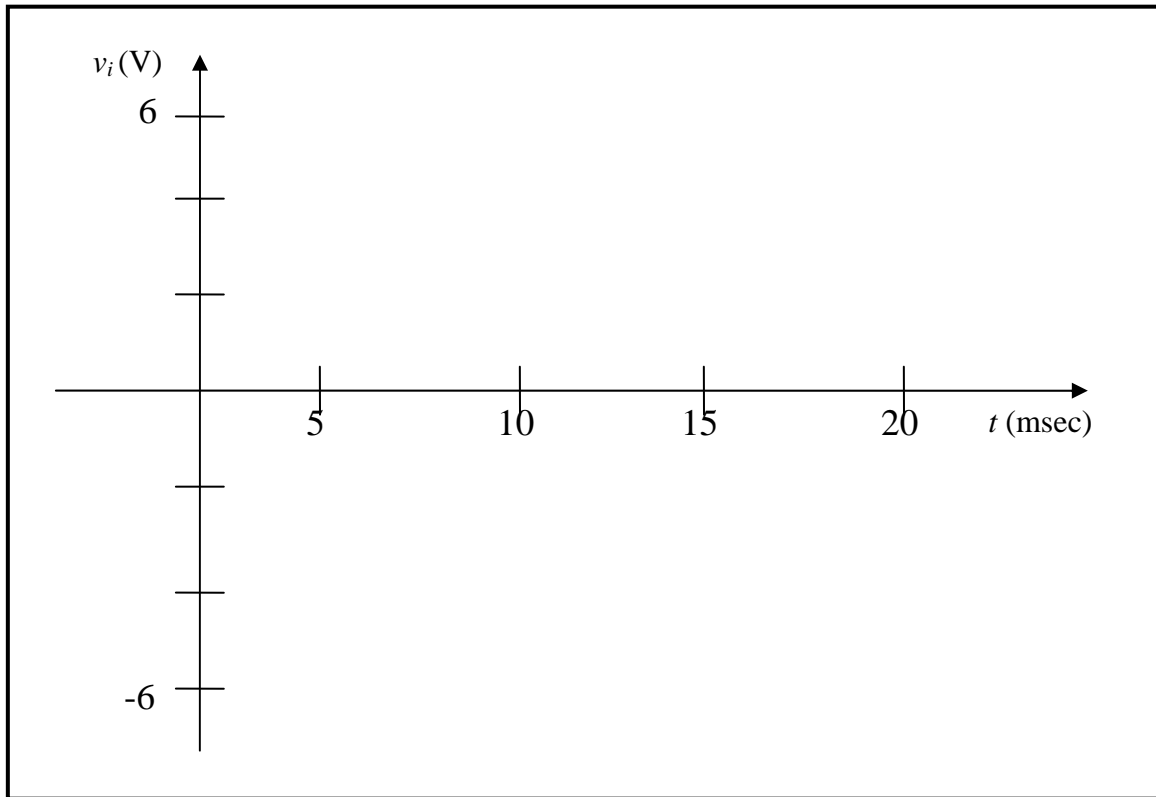


a.) Find the expression for $v_o(t)$ (piecewise expressions are acceptable) and plot $v_o(t)$ for $0\text{ msec} \leq t \leq 10\text{ msec}$. Label the values of $v_o(0^+)$, $v_o(5^-)$, and $v_o(5^+)$. **[20 pts]**

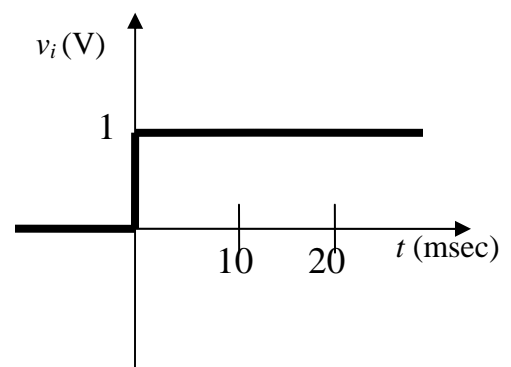
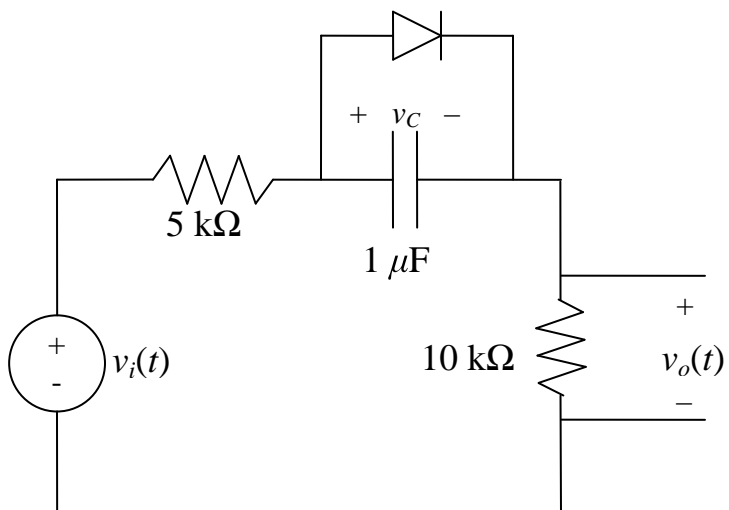
Show your work below. (Space for your answer is on the next page)

Answer:

Expression for $v_o(t)$:

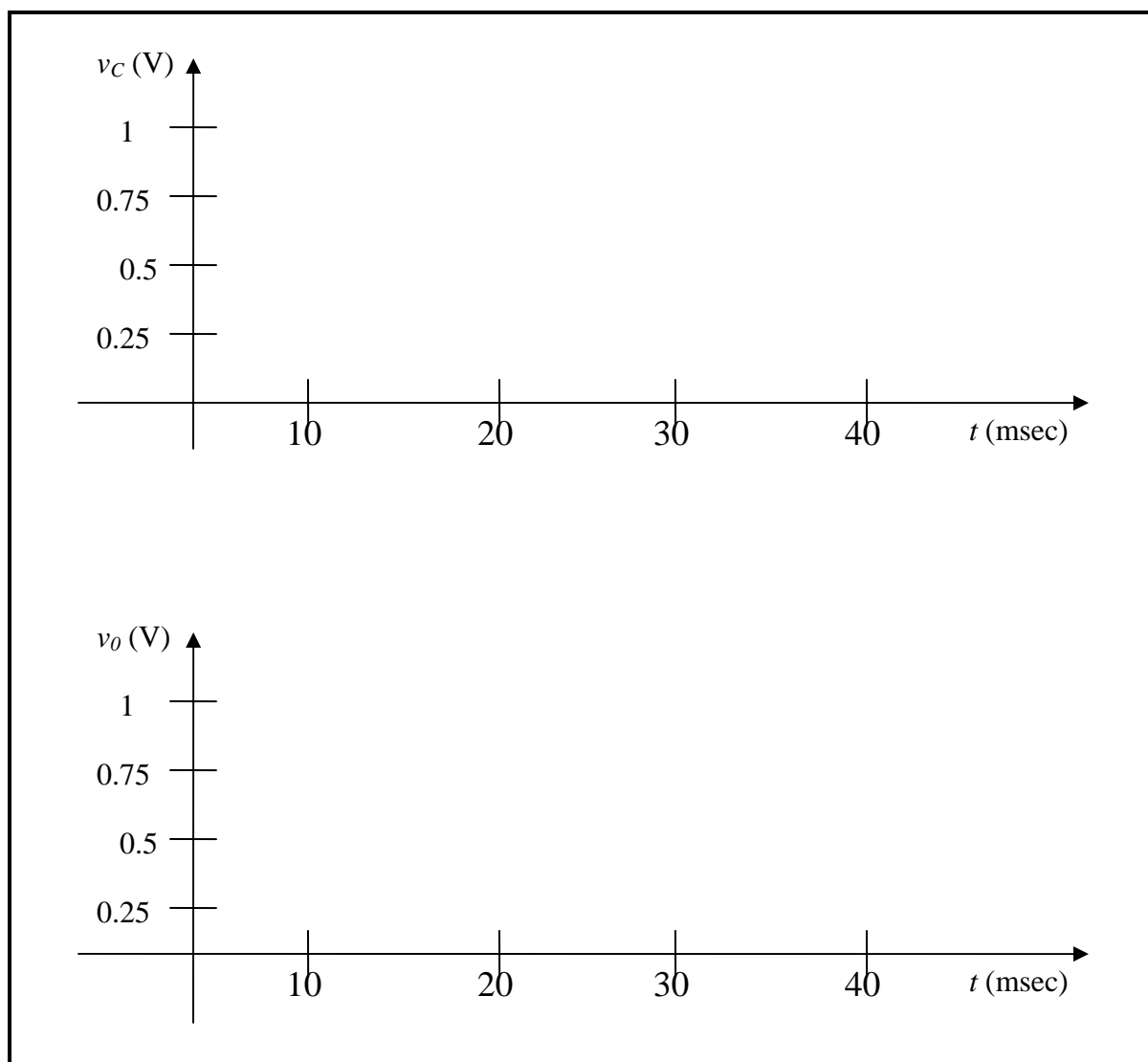


b.) Suppose we modify the circuit and apply a different input voltage.



On the axes below, plot for $v_C(t)$ and $v_o(t)$. Use the large signal model for the diode with a turn-on voltage, $V_D=0.7$ V. Label the following values: (1) the final voltage of v_C , (2) the time, t , when v_C reaches its final voltage, (3) the final voltage of v_o , and (4) the time, t , when v_o reaches its final voltage. **[10 points]**

Space for work:



Problem 4 [20 points]: Doping and Carrier Concentrations

Consider a Si sample maintained under thermal equilibrium conditions at $T = 300\text{K}$, doped with phosphorous at a concentration of $2 \times 10^{16} \text{ cm}^{-3}$.

a.) Is this material n-type or p-type? What are the majority and minority carrier concentrations? [4 pts]

Write your answers here:

type:
majority concentration:
minority carrier concentration:

b.) Suppose this sample is additionally doped with boron at a concentration of 10^{16} cm^{-3} . How will the carrier concentrations change? [3 pts]

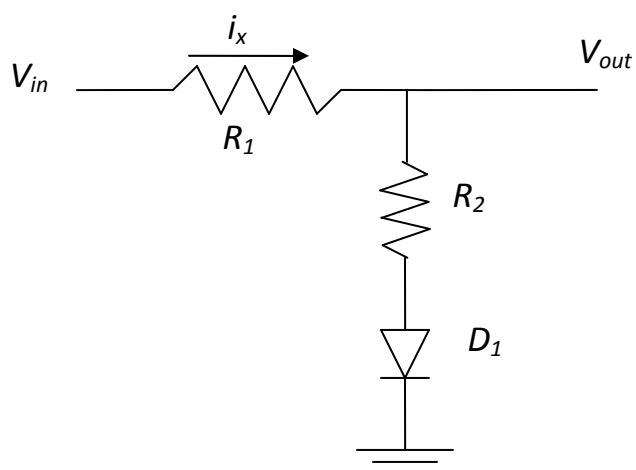
Write your answers here:

new majority concentration:
new minority carrier concentration:

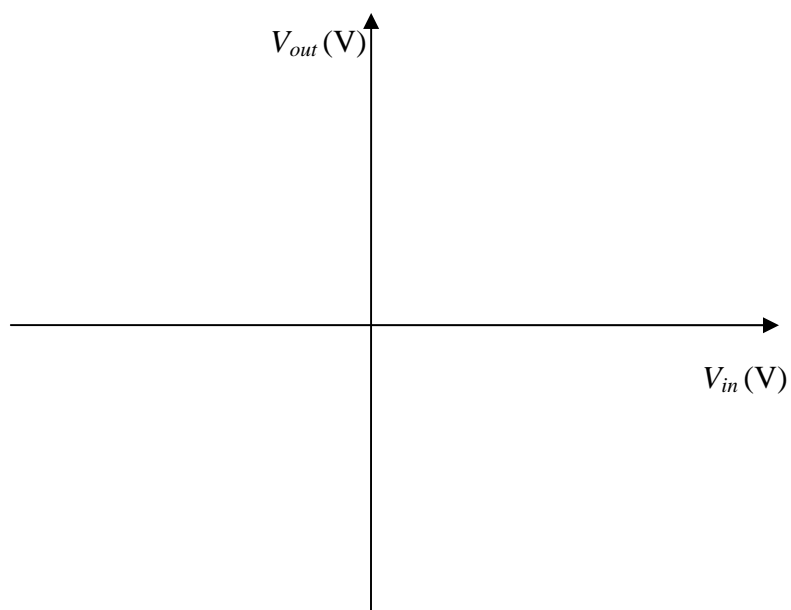
c.) Find the resistivity of this sample (with the boron doping). [4 pts]

Problem 5 [20 points]: Diode Circuits

Consider the following diode circuit:



a.) Using the large-signal model, plot V_{out} as function of V_{in} of the circuit below. Remember, a diode about to turn on carries zero current but sustains V_D . For full credit, you must label all important points on the graph (e.g. slope or cross-over points).



b.) Suppose $R_1 = 2 \text{ k}\Omega$, $R_2 = 2 \text{ k}\Omega$, and $V_D = 0.7 \text{ V}$ and V_{in} is given by the waveform shown below. Plot V_{out} on the given axes.

